Low temperature solution processed cobalt doped manganese oxide for high performance supercapacitor

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Cobalt doped manganese oxide (Co-Mn<sub>3</sub>O<sub>4</sub>) nanoparticles were synthesized by a facile low temperature solution process at 80 oC using cobalt chloride, potassium permanganate, urea and cetyltrimethylammonium bromide (CTAB). The synthesized Co-Mn<sub>3</sub>O<sub>4</sub> nanoparticles were well characterized in terms of morphology, crystallinity, structural, surface and electrochemical properties. The X-ray diffraction (XRD) revealed that the synthesized Co-Mn<sub>3</sub>O<sub>4</sub> showed slightly shifting as compared to undoped Mn<sub>3</sub>O<sub>4</sub>, confirming the Co doping in Mn<sub>3</sub>O<sub>4</sub>. From UV-Vis observations, the significant change in band gaps (Eg) from 2.07 eV to 3.1 eV was seen after Co doping in Mn<sub>3</sub>O<sub>4</sub>. Thermogravimetric analysis (TGA) results of Co-Mn<sub>3</sub>O<sub>4</sub> displayed the large weight loss as compared to undoped Mn<sub>3</sub>O<sub>4</sub>, indicating the evaporation of oxygen at higher temperature and doping of Co into these defects. The synthesized Co-Mn<sub>3</sub>O<sub>4</sub> nanoparticles were applied as working electrode for the fabrication of supercapacitors, which exhibited the good electrochemical and electrical properties as compared to undoped Mn<sub>3</sub>O<sub>4</sub>.